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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/708,371	02/26/2004	YI-JEN CHAN	11955-US-PA	2370

31561 7590 04/20/2006

JIANQ CHYUN INTELLECTUAL PROPERTY OFFICE  
7 FLOOR-1, NO. 100  
ROOSEVELT ROAD, SECTION 2  
TAIPEI, 100  
TAIWAN

EXAMINER

NGUYEN, LINH V

ART UNIT	PAPER NUMBER
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2819

DATE MAILED: 04/20/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

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<b>Office Action Summary</b>	<b>Application No.</b> 10/708,371	<b>Applicant(s)</b> CHAN ET AL.	
	<b>Examiner</b> Linh V. Nguyen	<b>Art Unit</b> 2819	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

**Period for Reply**

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

**Status**

- 1) ☒ Responsive to communication(s) filed on 14 February 2006.
- 2a) ☐ This action is **FINAL**.                      2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

**Disposition of Claims**

- 4) ☒ Claim(s) 1-15 is/are pending in the application.
- 4a) Of the above claim(s) \_\_\_\_\_ is/are withdrawn from consideration.
- 5) ☐ Claim(s) \_\_\_\_\_ is/are allowed.
- 6) ☒ Claim(s) 1-15 is/are rejected.
- 7) ☐ Claim(s) \_\_\_\_\_ is/are objected to.
- 8) ☐ Claim(s) \_\_\_\_\_ are subject to restriction and/or election requirement.

**Application Papers**

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☒ The drawing(s) filed on 26 February 2004 is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.  
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).  
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

**Priority under 35 U.S.C. § 119**

- 12) ☒ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☒ All    b) ☐ Some \*    c) ☐ None of:
1. ☒ Certified copies of the priority documents have been received.
2. ☐ Certified copies of the priority documents have been received in Application No. \_\_\_\_\_.
3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

\* See the attached detailed Office action for a list of the certified copies not received.

**Attachment(s)**

- |  |   |
|--|---|
| 1) <input checked="" type="checkbox"/> Notice of References Cited (PTO-892)  | 4) <input type="checkbox"/> Interview Summary (PTO-413)<br>Paper No(s)/Mail Date. _____ |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948)                                   | 5) <input type="checkbox"/> Notice of Informal Patent Application (PTO-152)             |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)<br>Paper No(s)/Mail Date _____ | 6) <input type="checkbox"/> Other: _____  |

### **DETAILED ACTION**

1. This office action is in response to communication filed on 2/14/06. Claims 1 – 15 are pending on this office action.

#### ***Specification***

2. The lengthy specification has not been checked to the extent necessary to determine the presence of all possible minor errors. Applicant's cooperation is requested in correcting any errors of which applicant may become aware in the specification.

#### ***Response to Arguments***

3. English translation of foreign priority filed 10/16/03 has been considered, but are moot in view of the new ground(s) of rejection.

#### ***Claim Rejections - 35 USC § 102***

4. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

5. Claims 1- 15 are rejected under 35 U.S.C. 102(b) as being anticipated by Ishikawa et al. U.S. patent No. 5,982,236.

Regarding claim 1, Fig. 5 of Ishikawa et al. discloses a power amplifier (Tr2) with an active bias circuit (4), comprising: a power amplifier transistor (Tr2)) with a gate (gate of Tr2) connected to a gate bias voltage (B); and an active bias circuit (4) connected to an input power terminal (A) and the gate of the power amplifier transistor

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(Gate of Tr2 ) for receiving an input power (output of 3) from the input power terminal (A) and outputting the gate bias voltage (B), to the gate wherein the gate bias voltage (gate of Tr2) is increased corresponding to an increase of the input power (Col. 12 lines 25 – 30) .

Regarding claim 4, wherein the power amplifier transistor (Tr2) and the active bias circuit (4) is manufactured by a system on chip process (Fig. 1).

Regarding claim 5, wherein the active bias circuit (4) comprises a diode (D11)) and a resistor (R11, R12).

Regarding claim 6, wherein an equivalent resistance of the diode in the active bias circuit varies in correspondence with the input power (this is an inherent characteristic of diode transistor D11, because the output of D11 varies according to RF input power (A) therefore the equivalent resistance of D11 must be varies according to power input A).

Regarding claim 7, Fig. 1 of Ishikawa et al.. discloses an integrated circuit for a power amplifier with an active bias circuit (Tr2)), comprising: a power output device (RF out); a power amplifier transistor (Tr2) with a gate (Gate of Tr2) connected to a gate bias voltage (B); an active bias circuit (4) connected to the power output device (RF out) and the gate of the power amplifier transistor (gate of Tr2) for receiving an input power (A) from the power output device (RF out) and providing a gate bias voltage (B) to the gate (gate of Tr2), wherein the gate bias voltage (4) is increased corresponding to an increase of the input power (Col. 12 lines 22 – 28); and a power input device (3)

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connected to an output terminal of the power amplifier transistor (Tr2) for receiving an amplified output power from the power amplifier transistor (Tr2).

Regarding claim 10, wherein the power amplifier transistor and the active bias circuit is manufactured by a system on chip process (Fig. 1).

Regarding claim 11, wherein the active bias circuit (4), comprises a diode (D11) and a resistor (R11, R12).

Regarding claim 12, wherein the equivalent resistance of the diode in the active bias circuit varies in correspondence with the input power (this is an inherent characteristic of diode transistor D11, because the output of D11 varies according to RF input power (A) therefore the equivalent resistance of D11 must be varies according to power input A).

Regarding claim 13, Fig. 1 Ishikawa et al. discloses method for generating a gate bias voltage (B) of a power amplifier transistor (Tr2) corresponding to an input power (A), comprising: providing an input power (A); and outputting a gate bias voltage (B) corresponding to the input power (A), wherein the gate bias voltage is increased corresponding to an increase of the input power (Col. 12 lines 22 – 28).

Regarding claims 2-3, 8-9 and 14 – 15, wherein a curve of an increase of the gate bias voltage versus the input power is a linear or non-linear curve. However Ishikawa et al. as applied to claims 1, 7 and 13 above disclosed the voltage bias for power amplifier transistor Tr2 is increase or decreasing according to increase or decrease of the Power input terminal A; therefore the curve of increase of the gate bias voltage of Ishikawa et al. must be either in the form of linear or non-linear curve. Further

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more Fig. 13(b) discloses a linear and non-linear curve of  $P_{out}$  at the power input terminal A; hence, voltage bias increase or decrease according to increase or decrease of linear or non-linear of  $P_{out}$ ; thereby, voltage bias (B) of power amplifier Tr2 must be increase or decrease linear or non-linear accordingly to increase or decrease of linear or non-linear of  $P_{out}$  at input power terminal A.

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**Prior Art**

6. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

**Contact Information**

7. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Linh Van Nguyen whose telephone number is (571) 272-1810. The examiner can normally be reached from 8:30 – 5:00 Monday-Friday. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Mr. Rexford Barnie can be reached at (571) 272-7492. The fax phone numbers for the organization where this application or proceeding is assigned are (571-273-8300) for regular communications and (571-273-8300) for After Final communications.

LINH NGUYEN  
PRIMARY EXAMINER

4/15/06

Linh Van Nguyen

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